# IF/UFRJ <br> Statistical Mechanics - 2024/1 - Raimundo 

## Problem Set \#5 - The Grand-Canonical Ensemble

8/4/2024

1. Consider a classical ideal gas of monatomic molecules.
(a) Show that the grand partition function is given by

$$
\mathcal{Z}=\mathrm{e}^{z Z_{1}},
$$

where $z$ is the fugacity, and $Z_{1}=V / \Lambda^{3}$ is the partition function for a single molecule, with $\Lambda=\left(h^{2} / 2 \pi m k_{B} T\right)^{1 / 2}$.
(b) Show that the average number of molecules is

$$
\langle N\rangle=z Z_{1}
$$

(c) Obtain the equation of state in terms of $\langle N\rangle$.
2. A fluid can coexist in the liquid and gas (vapour) phases. In order to describe this coexistence, we adopt a very simple model, in which we treat the liquid as a "gas" of independent molecules such that (i) the interaction of each molecule with the others is represented by a constant potential, $-\phi$; (ii) each one of the $N$ molecules of the liquid moves freely in a total volume $V_{\ell}=N_{\ell} v_{0}$, where $v_{0}$ is the (constant) volume per molecule in the liquid phase. The vapour of this liquid ( $N_{g}$ molecules in a volume $V_{g}$ ) is treated as a usual ideal gas.
(a) Treat each subsystem (liquid and vapour) in the canonical ensemble, and show that the vapour pressure is given by

$$
P=\frac{k_{\mathrm{B}} T}{v_{0}} \mathrm{e}^{-\beta \phi} .
$$

(b) Treat each subsystem (liquid and vapour) in the grand-canonical ensemble, and reobtain the above result. Comment on the differences between the approaches in (a) and (b).
(c) Discuss physically the behaviour of $P$ at low and high temperatures.
3. A monatomic gas coexists in equilibrium with the solid phase. Assume the energy per atom necessary to transform solid in gas is $\eta$, and adopt the Einstein model for solids, namely each atom vibrates around its equilibrium position with frequency $\omega$, being therefore represented by a three-dimensional harmonic oscillator. Determine the vapour pressure, $P$, as a function of temperature, $T$, for this system, and sketch $P(T)$. Discuss physically the low- and hightemperature limits.
4. Consider a monatomic crystal, made up of $N$ atoms. The atoms may be located in two kinds of positions: normal (filled circles in Fig. ??) or interstitial (empty circles). Assume there are an equal number, $N$, of both kinds of positions, but the energy of an atom on an interstitial position excedes by $\varepsilon$ that of an atom on a normal position.


Figure 1: Problem ?? - Lattice sites are represented by full circles, while intersticial sites are represented by empty circles.


Figure 2: Problem ?? -Gas molecules are adsorbed on a surface.
(a) Show that the partition function for this system can be written as

$$
\begin{equation*}
Z=\sum_{n} \Omega(n) \mathrm{e}^{-\beta n \varepsilon} \equiv \sum_{n} \zeta(n), \tag{1}
\end{equation*}
$$

where $n(1 \ll n \ll N)$ is the number of occupied interstitial positions, and $\Omega(n)$ is the number of ways these positions can be occupied.
(b) Show that the leading contribution to $\Omega(n)$ is

$$
\begin{equation*}
\Omega(n) \sim\left(\frac{N}{n}\right)^{2 n} \tag{2}
\end{equation*}
$$

(c) Since $\Omega(n)$ increases rapidly with $n$, while $\exp (-\beta n \varepsilon)$ decreases rapidly with $n$, one expects a sharp maximum of $\zeta(n)$ at some $n^{*}$. Show that

$$
\begin{equation*}
\frac{n^{*}}{N} \approx \mathrm{e}^{-\beta \varepsilon / 2} \tag{3}
\end{equation*}
$$

and that the Helmholtz free energy becomes

$$
\begin{equation*}
A \approx-k_{\mathrm{B}} T \ln \zeta\left(n^{*}\right) \tag{4}
\end{equation*}
$$

(d) Alternatively, we can calculate the Helmholtz free energy by first calculating the entropy, $S$, associated with displacing $n$ atoms to interstitial positions, and using $A=E-T S$. Show that imposing $A$ to be a minimum yields the same $n^{*}$ as in (c).
5. A surface with $M$ sites can adsorb atoms of an ideal gas (single atoms with mass $m$ ) at a temperature $T$ and pressure $P$; see Fig. ??. An adsorbed atom has energy $-\varepsilon_{0}$, relative to the free case.
(a) Obtain an expression for the surface coverage, $\theta$, (i.e., the ratio of the number of adsorbed atoms by $M$, the number of adsorbing sites) as a function of $P, T$, and $\varepsilon_{0}$.
(b) Discuss physically the behaviour of $\theta$ in the limits $P \rightarrow 0$ and $P \rightarrow \infty$.

